

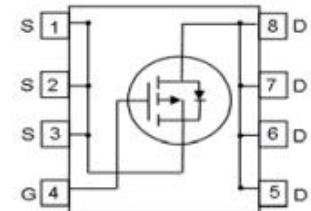
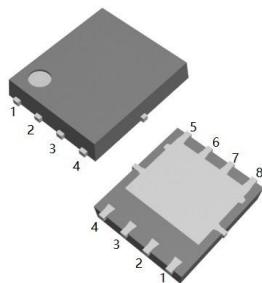
D40P03HL

-40 Amps,-30 Volts P-CHANNEL MOSFET

FEATURE

- -40A,-30V, $R_{DS(ON)MAX}=8\text{m}\Omega$ @ $V_{GS}=-10\text{V}/-10\text{A}$
 $R_{DS(ON)MAX}=11\text{m}\Omega$ @ $V_{GS}=-4.5\text{V}/-10\text{A}$
- Low gate charge
- Low C_{iss}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

DFN3*3



Absolute Maximum Ratings($T_C=25^\circ\text{C}$,unless otherwise noted)

Parameter	Symbol	D40P03HL	UNIT
Drain-Source Voltage	V_{DSS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current	I_D	-40	A
Pulsed Drain Current(Note1)	I_{DM}	-160	
Single Pulse Avalanche Energy (Note 2)	E_{AS}	150	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C
Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	T_L	260	°C

Thermal Characteristics

Parameter	Symbol	D40P03HL	Units
Thermal resistance , Junction to Case	$R_{th(J-c)}$	2.6	°C/W
Maximum Power Dissipation	$T_C=25^\circ\text{C}$	P_D	W

Electrical Characteristics (T_c=25°C,unless otherwise noted)

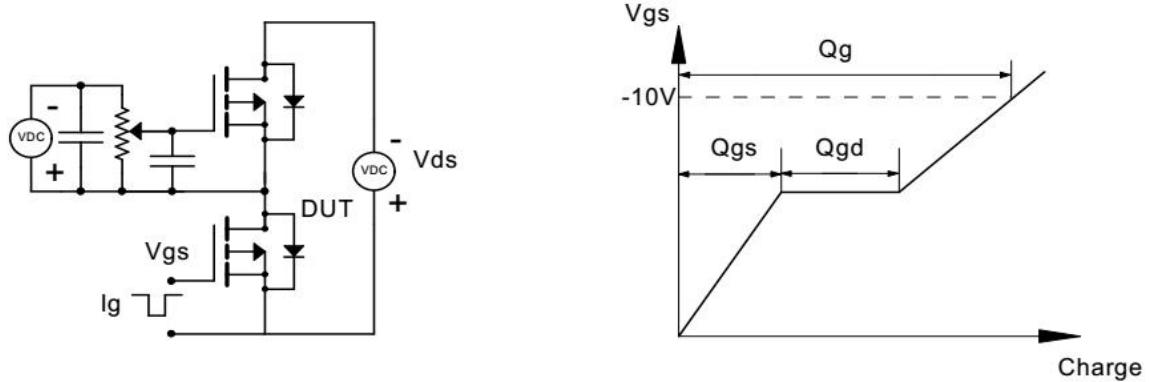
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-30	—	—	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	—	—	-1	uA
Gate-Body Leakage Current,Forward	I _{GSSF}	V _{GS} =20V,V _{DS} =0V	—	—	100	nA
Gate-Body Leakage Current,Reverse	I _{GSSR}	V _{GS} =-20V,V _{DS} =0V	—	—	-100	nA
On Characteristics						
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250uA	-1.0	—	-2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-10A	—	6	8	mΩ
		V _{GS} =-4.5V,I _D =-10A	—	9	11	
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =-25V,V _{GS} =0V, f=1.0MHZ	—	2303	—	pF
Output Capacitance	C _{oss}		—	316	—	pF
Reverse Transfer Capacitance	C _{rss}		—	287	—	pF
Switching Characteristics						
Turn-On Delay Time	t _{d(on)}	V _{DD} =-15V,I _D =-20A, V _{GS} =-10V, R _G =3.7 Ω	—	12	—	ns
Turn-On Rise Time	t _r		—	4	—	ns
Turn-Off Delay Time	t _{d(off)}		—	67	—	ns
Turn-Off Fall Time	t _f		—	37	—	ns
Total Gate Charge	Q _g	V _{DS} =-15V,V _{GS} =-10V, I _D =-20A	—	61	—	nC
Gate-Source Charge	Q _{gs}		—	10	—	nC
Gate-Drain Charge	Q _{gd}		—	15	—	nC
Drain-Source Body Diode Characteristics and Maximum Ratings						
Continuous Diode Forward Current	I _s		—	—	-40	A
Pulsed Diode Forward Current	I _{SM}		—	—	-160	A
Diode Forward Voltage	V _{SD}	I _s =-1A,V _{GS} =0V	—	—	-1.2	V
Reverse Recovery Time	t _{rr}	V _{GS} =0V,I _s =-5A, dI _F /dt=100A/us,(Note3)	—	25	—	ns
Reverse Recovery Charge	Q _{rr}		—	23	—	uC

Notes

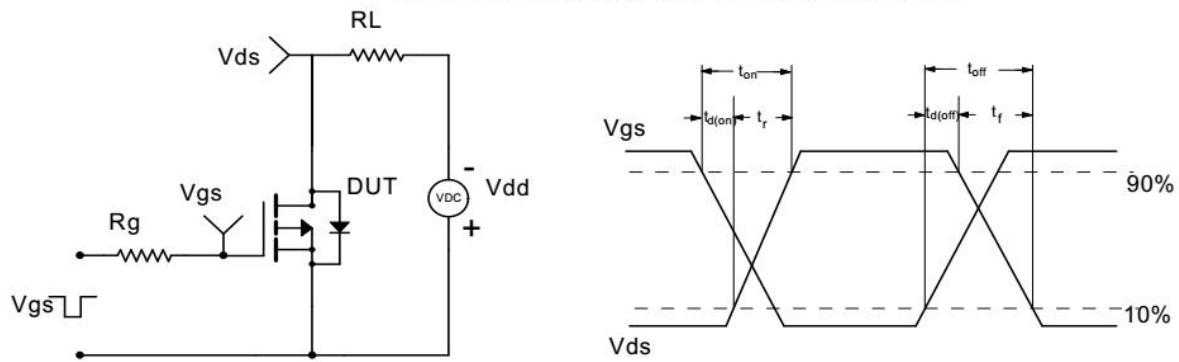
1. Repetitive Rating:pulse width limited by maximum junction temperature .
2. L=0.5mH,R_g=25 Ω , T_J=25 °C.
3. Pulse width≤300us;duty cycle≤2%.

Test Circuit and Waveform

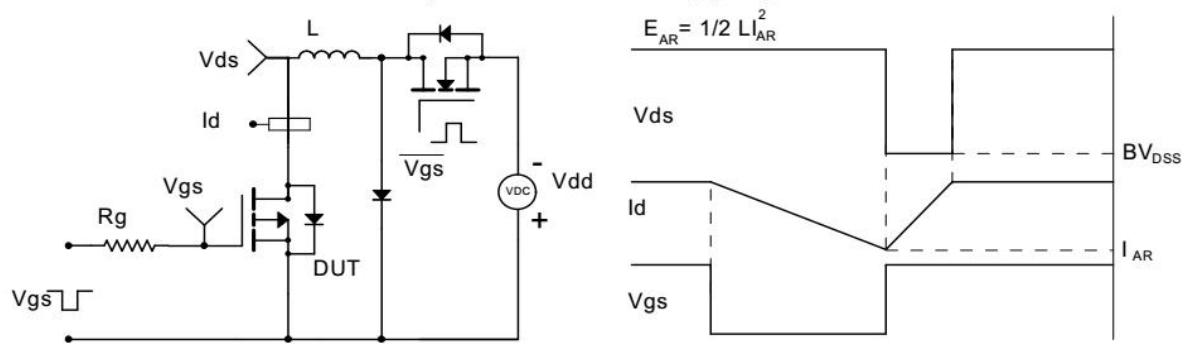
Gate Charge Test Circuit & Waveform



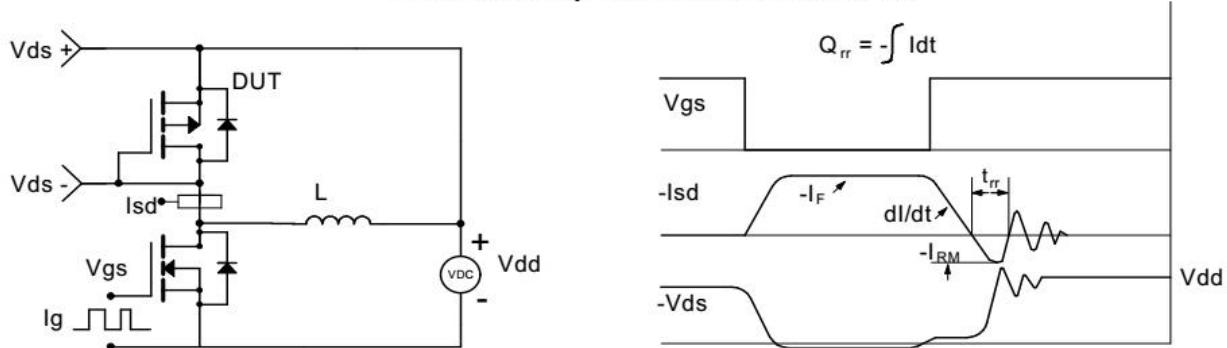
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms



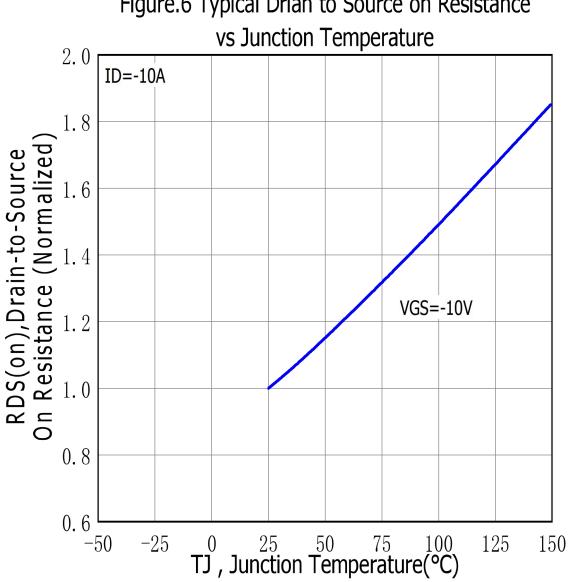
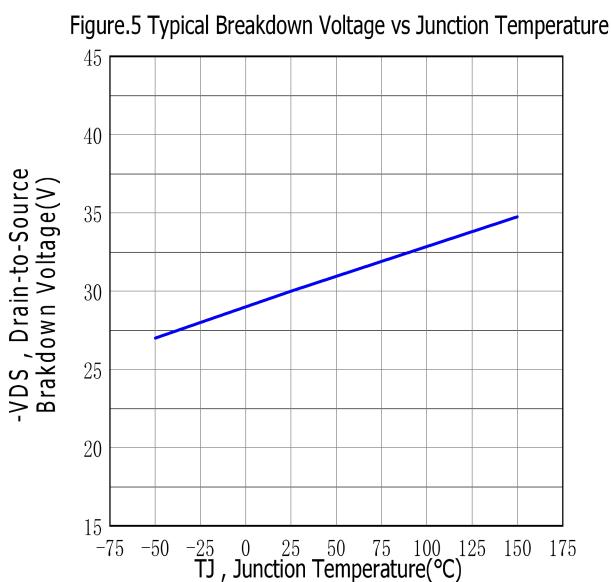
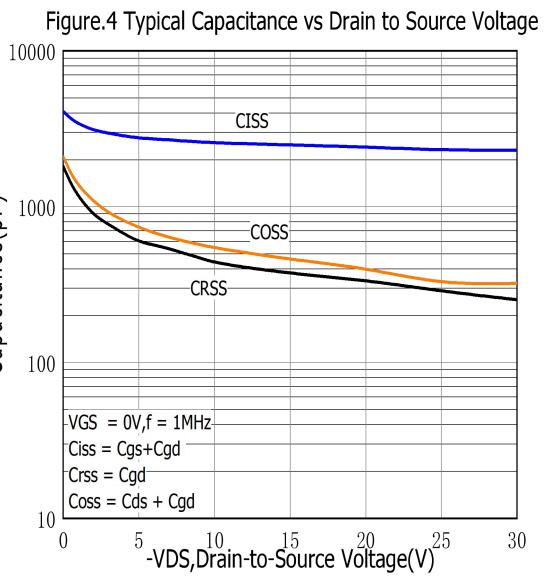
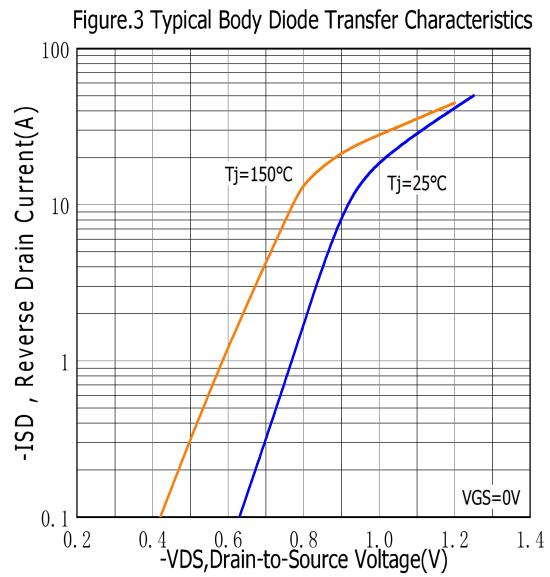
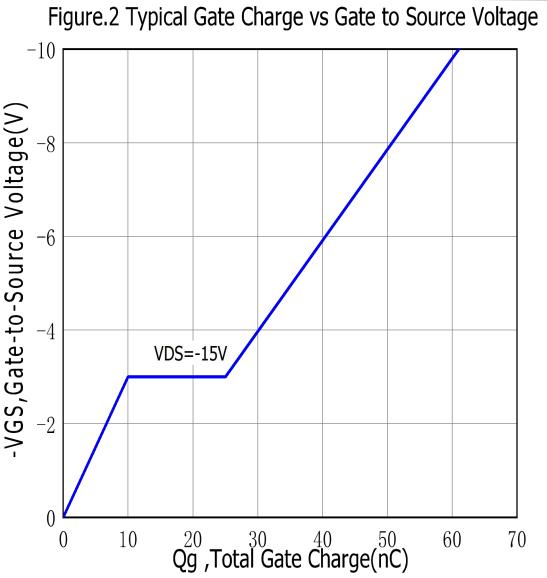
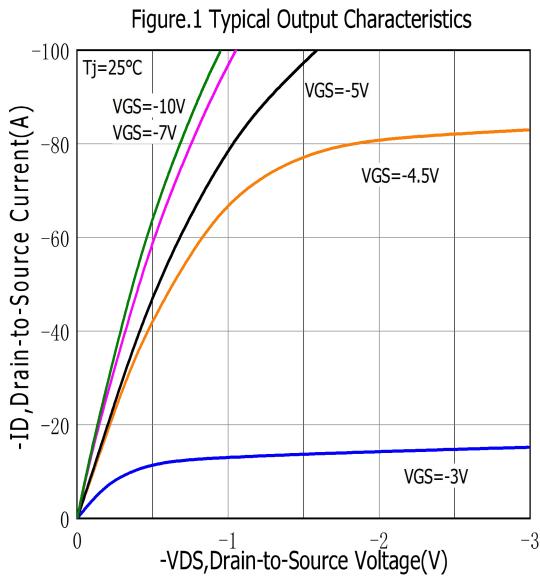


Figure.7 Maximum Forward Bias Safe Operating Area

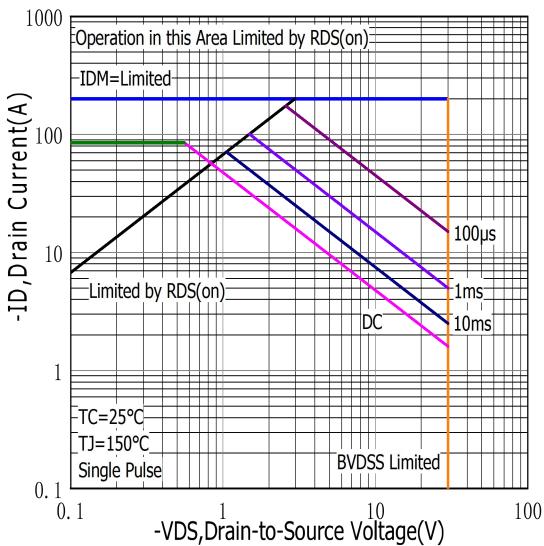


Figure.8 Typical Drain to Source ON Resistance vs Drain Current

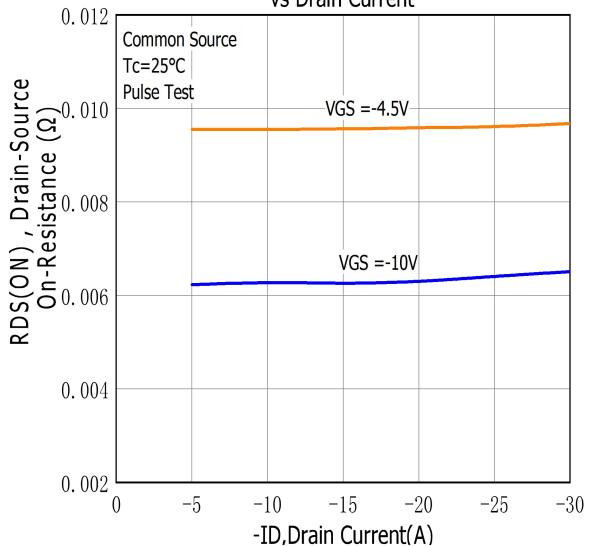


Figure.9 Maximum EAS vs Channel Temperature

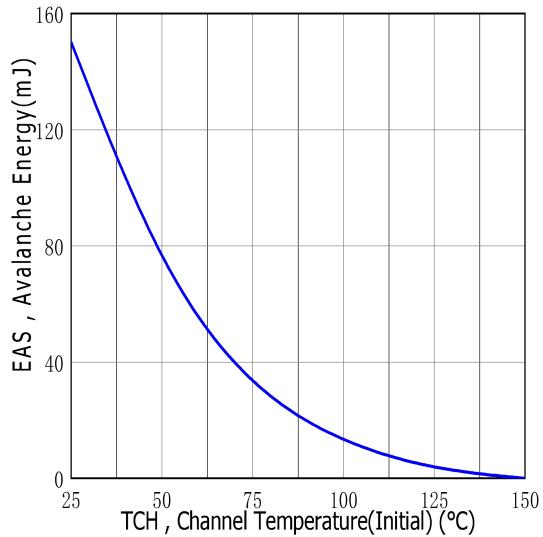


Figure.10 Typical Threshold Voltage vs Case Temperature

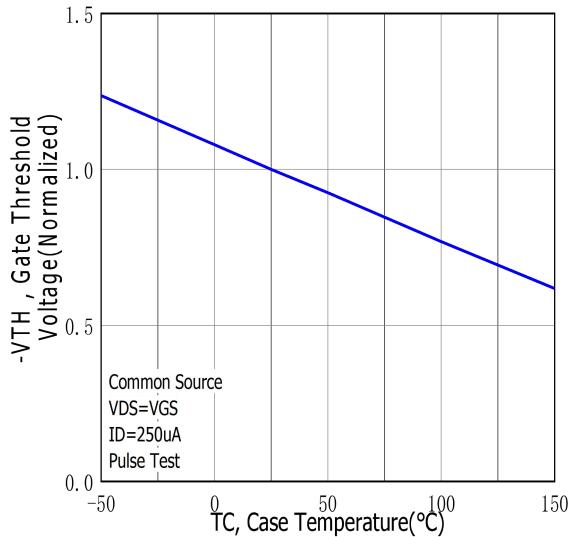


Figure.11 Maximum Effective Thermal Impedance , Junction to Case

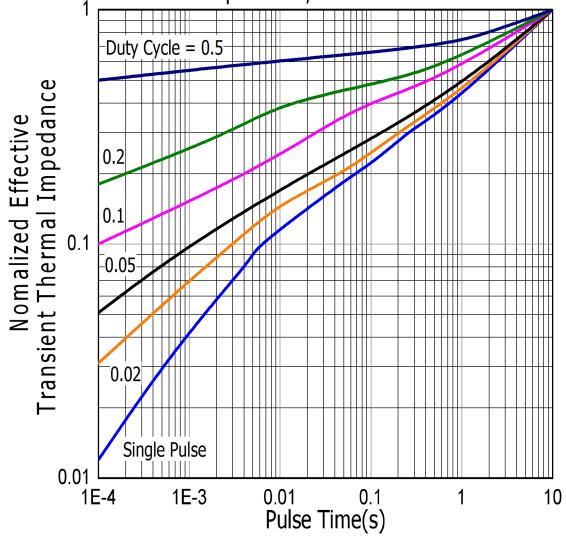
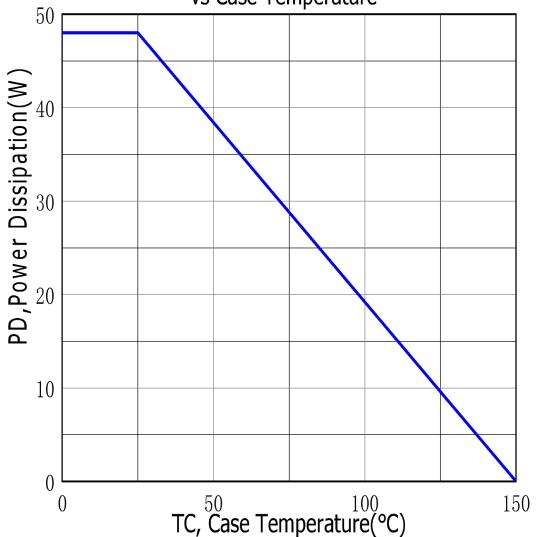
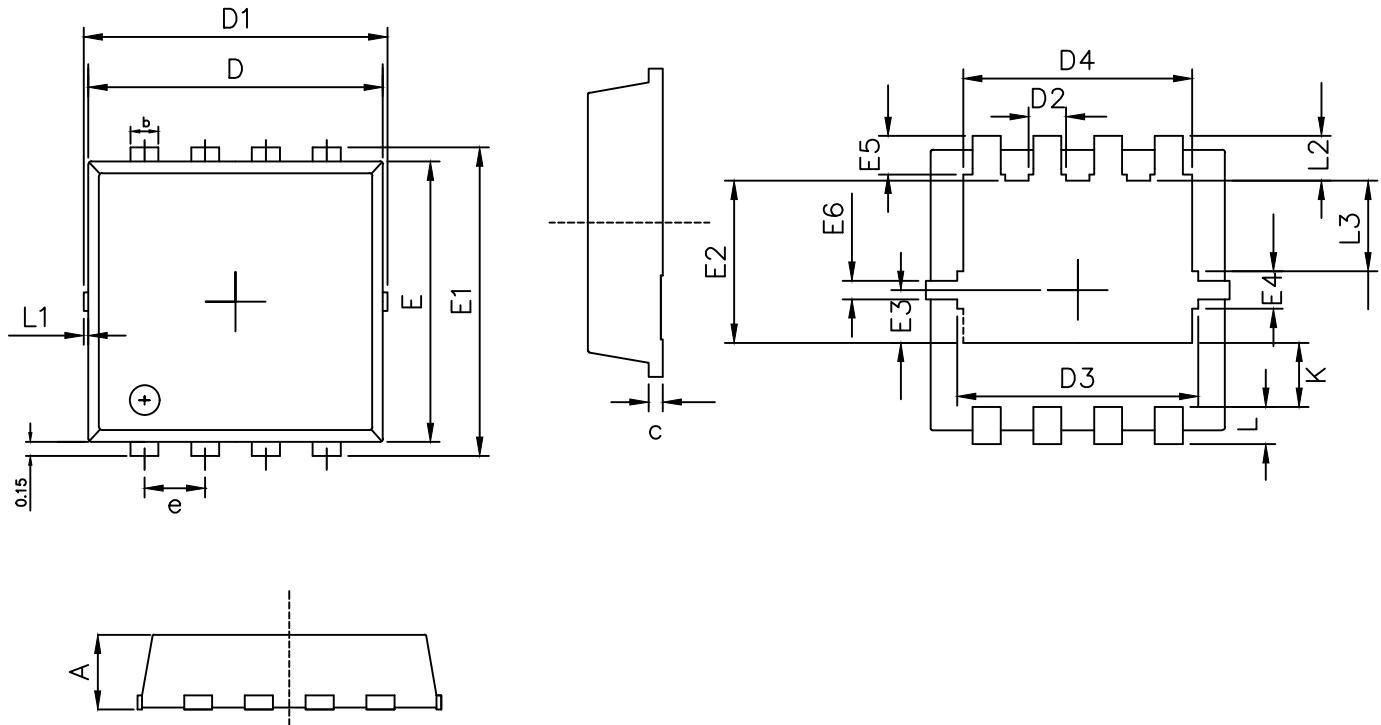


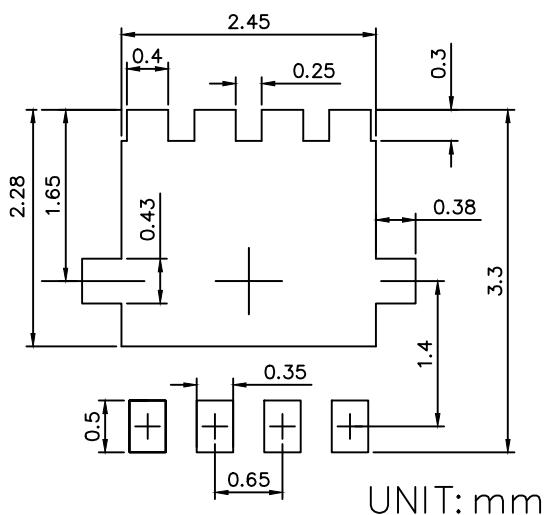
Figure.12 Maximum Power Dissipation vs Case Temperature



DFN3x3 PACKAGE OUTLINE



RECOMMENDED LAND PATTERN



	MIN	NOM	MAX
A	0.70	0.85	1.00
b	0.24	0.30	0.40
c	0.10	0.15	0.25
D	3.00	3.15	3.25
D1	3.10	3.25	3.50
D2	0.30	0.40	0.50
D3	2.50	2.58	2.70
D4	2.35	2.45	2.55
E	2.90	3.00	3.10
E1	3.15	3.30	3.45
E2	1.65	1.75	1.85
E3	0.48	0.58	0.68
E4	0.23	0.40	0.50
E5	0.20	0.30	0.40
E6	0.075	0.17	0.25
e	0.55	0.65	0.75
K	0.52	0.72	0.82
L	0.25	0.40	0.55
L1	0.00	0.05	0.10
L2	0.28	0.43	0.58
L3	0.88	0.98	1.08